



ZXTN25012EZ

12V NPN HIGH GAIN TRANSISTOR IN SOT89

Features

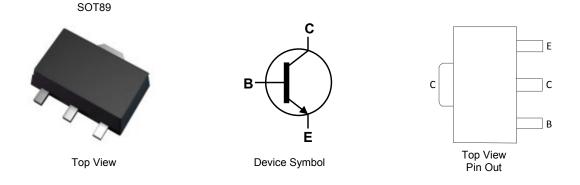
- BV_{CEO} > 12V
- Low Saturation Voltage V_{CE(sat)} < 38mV @ 1A
- I_C = 6.5A High Continuous Current
- P_D = 2.4W Power Dissipation
- R_{sat} = 25mΩ for a Low Equivalent On-Resistance
- Complementary part number: ZXTP25012EZ
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen- and Antimony-Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>

Application

- LED driving
- Motor driving
- Boost converters
- Royer converters
- Camera strobe
- MOSFET gate drivers

Mechanical Data

- Case: SOT89
- Case Material: Molded Plastic. "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 3
- Weight: 0.05 grams (Approximate)



Ordering Information (Note 4)

Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity Per Reel
ZXTN25012EZTA	Standard	1K7	7	12	1,000

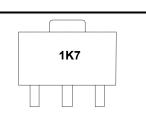
No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
 See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

Notes:



1K7 = Product Type Marking Code



Absolute Maximum Ratings (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	20	V
Collector-Emitter Voltage	V _{CEO}	12	V
Emitter-Collector Voltage (reverse blocking)	V _{ECX}	6	V
Emitter-Base Voltage	V _{EBO}	7	V
Continuous Collector Current	lc	6.5	A
Peak Pulse Collector Current (single pulse)	I _{CM}	15	A
Base Current	Ι _Β	1	A

Thermal Characteristics (@ T_A = +25°C, unless otherwise specified.)

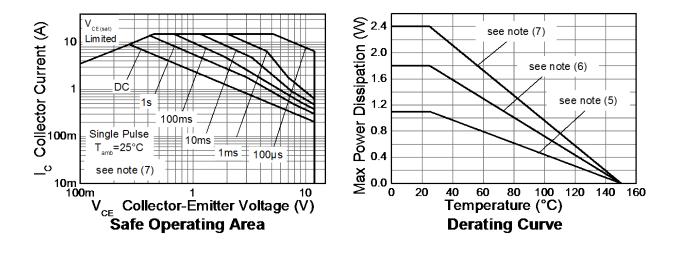
Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5) Linear Derating Factor	PD	1.1 8.8	W mW/°C
Power Dissipation (Note 6) Linear Derating Factor	PD	1.8 14.4	W mW/°C
Power Dissipation (Note 7) Linear Derating Factor	PD	2.4 19.2	W mW/°C
Power Dissipation (Note 8) Linear Derating Factor	PD	4.46 35.7	W mW/°C
Power Dissipation (Note 9) Linear Derating Factor	PD	19.2 153	W mW/°C
Thermal Resistance, Junction to Ambient (Note 5)	R _{0JA}	117	°C/W
Thermal Resistance, Junction to Ambient (Note 6)	R _{0JA}	68	°C/W
Thermal Resistance, Junction to Ambient (Note 7)	R _{0JA}	51	°C/W
Thermal Resistance, Junction to Ambient (Note 8)	R _{0JA}	28	°C/W
Thermal Resistance, Junction to Case (Note 9)	R _{ejc}	7.95	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C

5. For a device surface mounted on 15mm x 15mm x 0.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions; device Notes: measured when operating in steady state condition.
Same as note (5), except the device is mounted on 25mm x 25mm x 0.6mm single sided 1oz weight copper.
Same as note (5), except the device is mounted on 50mm x 50mm x 0.6mm single sided 1oz weight copper.

Same as note (5), except the device is measured at t<5 seconds.
 Junction to case (collector tab). Typical.

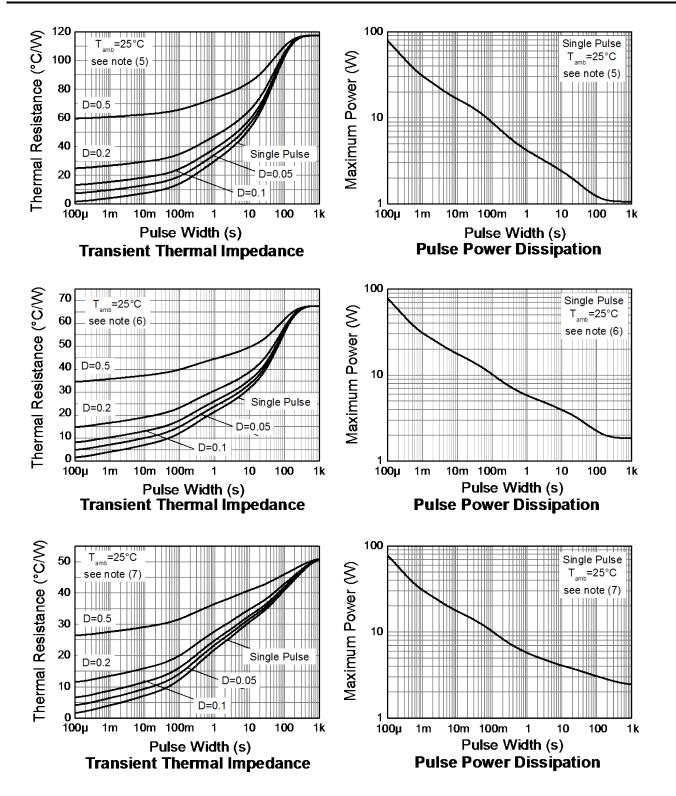


Thermal Characteristics and Derating Information





Thermal Characteristics and Derating Information (cont.)





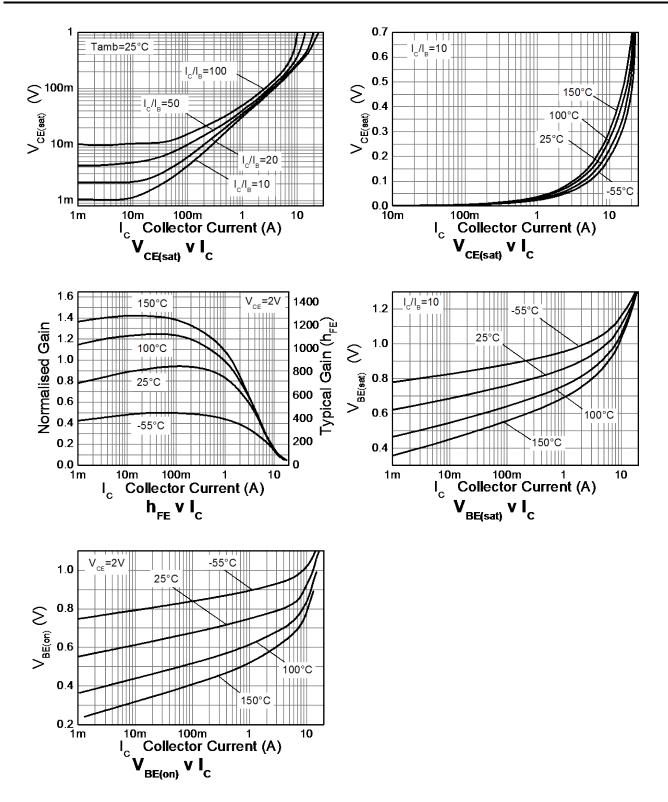
Electrical Characteristics (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	20	40	_	V	I _C = 100μA
Collector-Emitter Breakdown Voltage (Note 10)	BV _{CEO}	12	17	_	V	$I_{\rm C}$ = 10mA
Emitter-Collector breakdown voltage (reverse blocking)	BV _{ECX}	6	8	_	V	I_E = 100mA, R_{BC} < 1kΩ or 0.25V > V _{BC} > -0.25V
Emitter-Collector breakdown voltage (reverse blocking)	BV _{ECO}	4.5	5.5	_	V	I _E = 100μΑ
Emitter-Base Breakdown Voltage	BV _{EBO}	7	8.3	—	V	I _E = 100μA
Collector-Base Cutoff Current	I _{CBO}	_	1	50 0.5	nA μA	V _{CB} = 20V V _{CB} = 20V, T _A = +100°C
Collector-Emitter Cutoff Current	I _{CEX}	_	_	100	nA	V_{CE} = 20V, R_{BE} < 1k Ω or -1V < V_{BE} < 0.25V
Emitter Cutoff Current	I _{EBO}		1	50	nA	V _{EB} = 5.6V
Collector-Emitter Saturation Voltage (Note 10)	V _{CE(sat)}	_	31 50 70 90 200	38 60 85 130 270	mV	$I_{C} = 1A, I_{B} = 100MA$ $I_{C} = 1A, I_{B} = 10MA$ $I_{C} = 2A, I_{B} = 40MA$ $I_{C} = 2A, I_{B} = 20MA$ $I_{C} = 6.5A, I_{B} = 130MA$
Base-Emitter Saturation Voltage (Note 10)	V _{BE(sat)}		950	1050	mV	I _C = 6.5A, I _B = 130mA
Base-Emitter Turn-On Voltage (Note 10)	V _{BE(on)}		840	950	mV	I _C = 6.5A, V _{CE} = 2V
DC Current Gain (Note 10)	hFE	500 500 185 30	800 750 250 50	1500 — — —	_	$I_{C} = 10mA, V_{CE} = 2V$ $I_{C} = 1A, V_{CE} = 2V$ $I_{C} = 6.5A, V_{CE} = 2V$ $I_{C} = 15A, V_{CE} = 2V$
Transitional frequency	f _T	_	260	_	MHz	I _C = 50mA, V _{CE} = 10V, f = 100MHz
Input Capacitance	Ci _{bo}	_	137	250	pF	V _{EB} = 0.5V, f = 1MHz
Output Capacitance	Cobo	—	25	35	pF	V _{CB} = 10V, f = 1MHz
Delay time	t _d	_	71	—	ns	
Rise time	tr	_	70	—	ns	V _{CC} = 10V, I _C = 1A,
Storage time	ts		233	—	ns	$I_{B1} = -I_{B2} = 10mA$
Fall time	t _f	_	72	_	ns	

Note: 10. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.



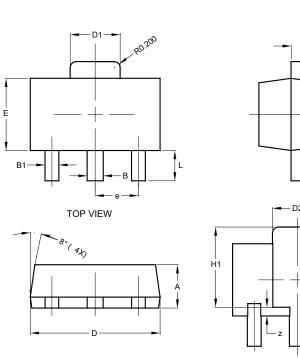
Typical Electrical Characteristics (@ T_A = +25°C, unless otherwise specified.)

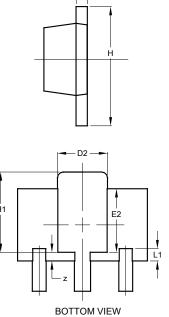




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

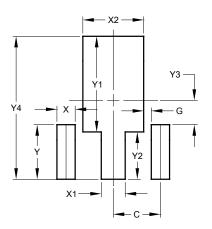




SOT89					
Dim	Min	Max	Тур		
Α	1.40	1.60	1.50		
В	0.50	0.62	0.56		
B1	0.42	0.54	0.48		
С	0.35	0.43	0.38		
D	4.40	4.60	4.50		
D1	1.62	1.83	1.733		
D2	1.61	1.81	1.71		
Е	2.40	2.60	2.50		
E2	2.05	2.35	2.20		
е	-	-	1.50		
н	3.95	4.25	4.10		
H1	2.63	2.93	2.78		
L	0.90	1.20	1.05		
L1	0.327	0.527	0.427		
z	0.20	0.40	0.30		
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)	
С	1.500	
G	0.244	
Х	0.580	
X1	0.760	
X2	1.933	
Y	1.730	
Y1	3.030	
Y2	1.500	
Y3	0.770	
Y4	4.530	

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